

# DATA SHEET

# NEC

# MOS FIELD EFFECT TRANSISTOR $\mu$ PA2742GR

## SWITCHING N-CHANNEL POWER MOSFET

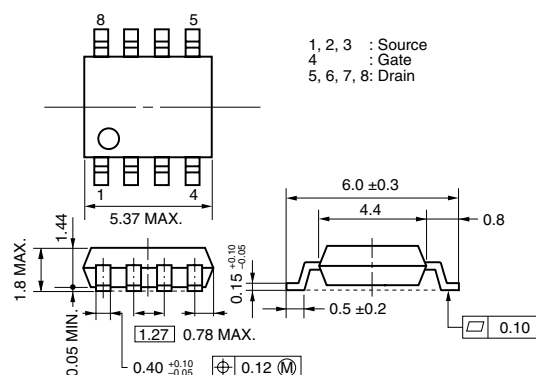
### DESCRIPTION

The  $\mu$ PA2742GR is N-channel MOS Field Effect Transistor designed for power management applications of a notebook computer.

### FEATURES

- Low on-state resistance  
 $R_{DS(on)1} = 4.8 \text{ m}\Omega \text{ MAX. (} V_{GS} = 10 \text{ V, } I_D = 9 \text{ A)}$   
 $R_{DS(on)2} = 8.0 \text{ m}\Omega \text{ MAX. (} V_{GS} = 6 \text{ V, } I_D = 9 \text{ A)}$
- Low input capacitance  
 $C_{iss} = 4600 \text{ pF TYP. (} V_{DS} = 10 \text{ V, } V_{GS} = 0 \text{ V)}$
- Built-in gate protection diode
- Small and surface mount package (Power SOP8)
- RoHS Compliant

### PACKAGE DRAWING (Unit: mm)



### ORDERING INFORMATION

PART NUMBER	LEAD PLATING	PACKING	PACKAGE
$\mu$ PA2742GR-E1-AT <sup>Note</sup>	Pure Sn	Tape 2500 p/reel	Power SOP8
$\mu$ PA2742GR-E2-AT <sup>Note</sup>			0.08 g TYP.

**Note** Pb-free (This product does not contain Pb in the external electrode and other parts.)

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ , All terminals are connected.)

Drain to Source Voltage ( $V_{GS} = 0 \text{ V}$ )	$V_{DSS}$	35	V
Gate to Source Voltage ( $V_{DS} = 0 \text{ V}$ )	$V_{GSS}$	$\pm 25$	V
Drain Current (DC)	$I_{D(DC)}$	$\pm 17$	A
Drain Current (pulse) <sup>Note1</sup>	$I_{D(pulse)}$	$\pm 150$	A
Total Power Dissipation <sup>Note2</sup>	$P_{T1}$	1.1	W
Total Power Dissipation ( $PW = 10 \text{ sec}$ ) <sup>Note2</sup>	$P_{T2}$	2.5	W
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	$-55 \text{ to } +150$	$^\circ\text{C}$
Single Avalanche Current <sup>Note3</sup>	$I_{AS}$	17	A
Single Avalanche Energy <sup>Note3</sup>	$E_{AS}$	28.9	mJ

**Notes 1.**  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$

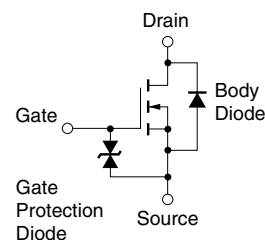
**2.** Mounted on FR-4 board of 25.4 mm x 25.4 mm x 0.8 mm

**3.** Starting  $T_{ch} = 25^\circ\text{C}$ ,  $V_{DD} = 17.5 \text{ V}$ ,  $R_G = 25 \Omega$ ,  $V_{GS} = 20 \rightarrow 0 \text{ V}$ ,  $L = 100 \mu\text{H}$

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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### EQUIVALENT CIRCUIT

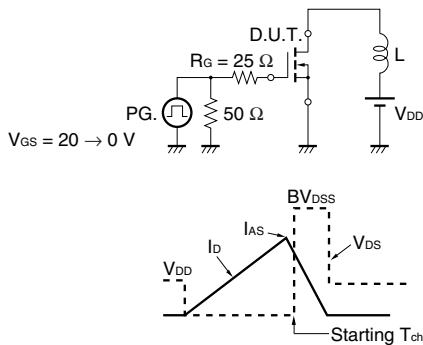


**ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)**

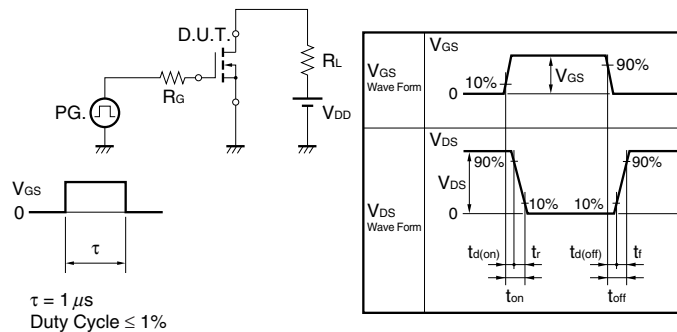
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 35 V, V <sub>GS</sub> = 0 V			1	μA
Gate Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> = ±20 V, V <sub>DS</sub> = 0 V			±10	μA
Gate to Source Cut-off Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 1 mA	2.0		3.0	V
Forward Transfer Admittance <sup>Note</sup>	Y <sub>fs</sub>	V <sub>DS</sub> = 10 V, I <sub>D</sub> = 9 A	9			S
Drain to Source On-state Resistance <sup>Note</sup>	R <sub>DS(on)1</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 9 A		4	4.8	mΩ
	R <sub>DS(on)2</sub>	V <sub>GS</sub> = 6 V, I <sub>D</sub> = 9 A		4.7	8.0	mΩ
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 10 V,		4600		pF
Output Capacitance	C <sub>oss</sub>	V <sub>GS</sub> = 0 V,		830		pF
Reverse Transfer Capacitance	C <sub>rss</sub>	f = 1 MHz		530		pF
Turn-on Delay Time	t <sub>d(on)</sub>	V <sub>DD</sub> = 17.5 V, I <sub>D</sub> = 9 A,		27		ns
Rise Time	t <sub>r</sub>	V <sub>GS</sub> = 10 V,		35		ns
Turn-off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> = 10 Ω		99		ns
Fall Time	t <sub>f</sub>			41		ns
Total Gate Charge	Q <sub>G</sub>	V <sub>DD</sub> = 17.5 V,		43		nC
Gate to Source Charge	Q <sub>GS</sub>	V <sub>GS</sub> = 5 V,		14		nC
Gate to Drain Charge	Q <sub>GD</sub>	I <sub>D</sub> = 17 A		22		nC
Body Diode Forward Voltage <sup>Note</sup>	V <sub>F(S-D)</sub>	I <sub>F</sub> = 17 A, V <sub>GS</sub> = 0 V			1.2	V
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> = 17 A, V <sub>GS</sub> = 0 V,		37		ns
Reverse Recovery Charge	Q <sub>rr</sub>	di/dt = 100 A/μs		37		nC

Note Pulsed

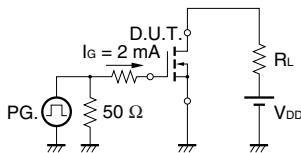
**TEST CIRCUIT 1 AVALANCHE CAPABILITY**



**TEST CIRCUIT 2 SWITCHING TIME**

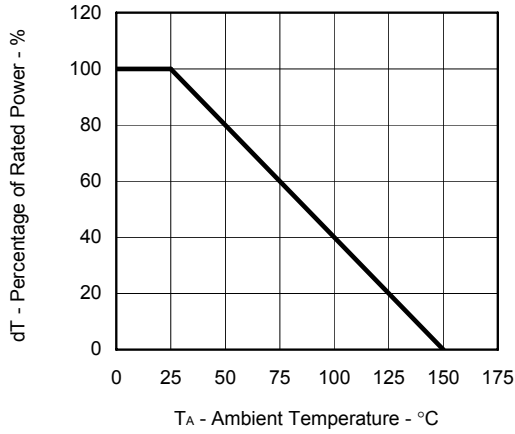


**TEST CIRCUIT 3 GATE CHARGE**

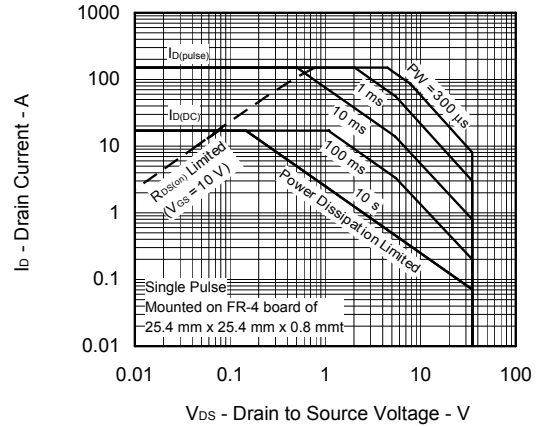


TYPICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

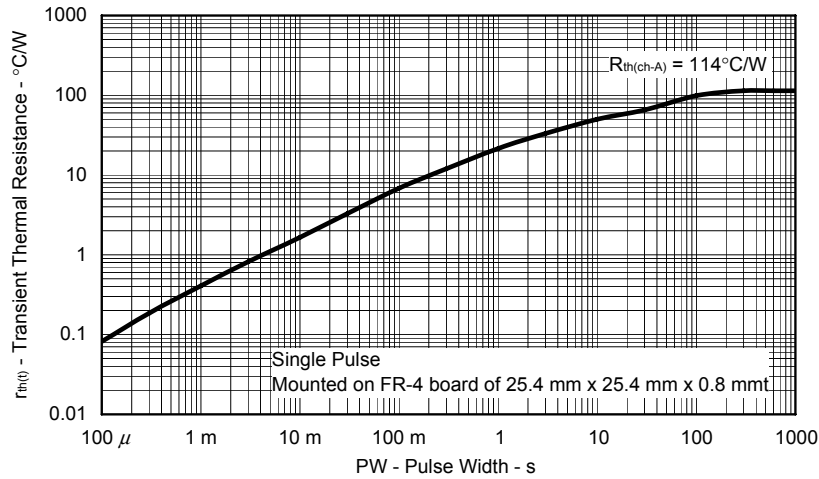
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



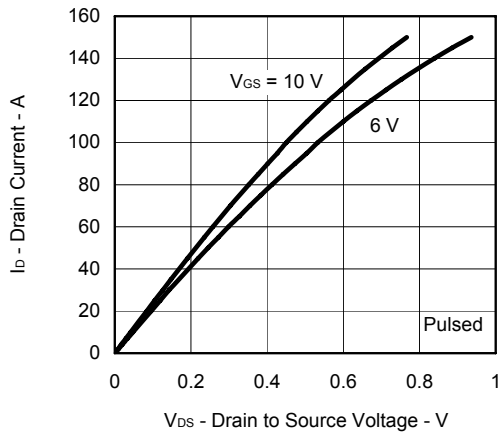
FORWARD BIAS SAFE OPERATING AREA



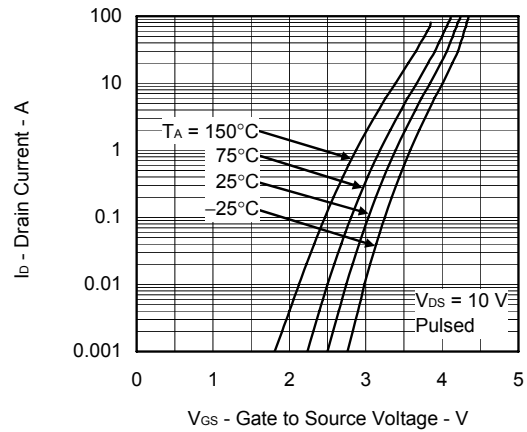
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

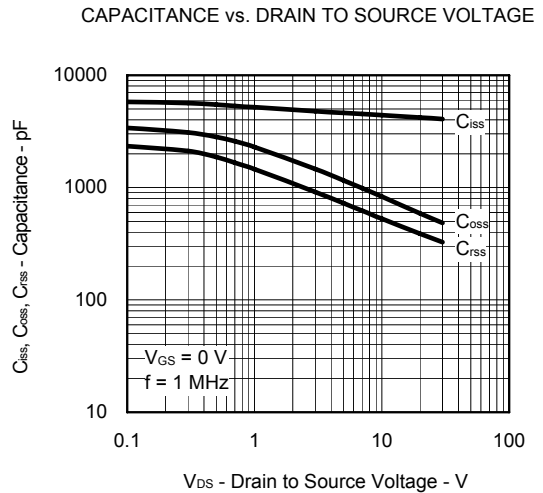
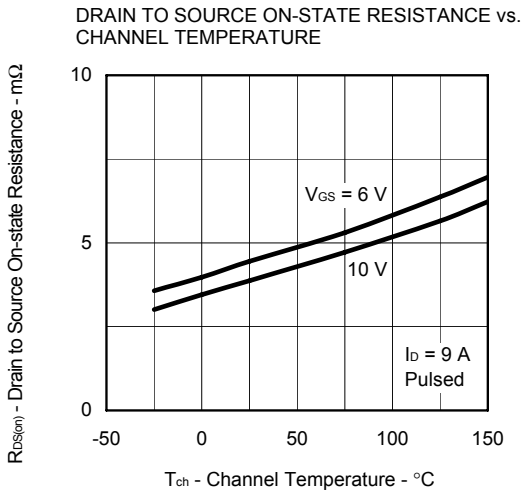
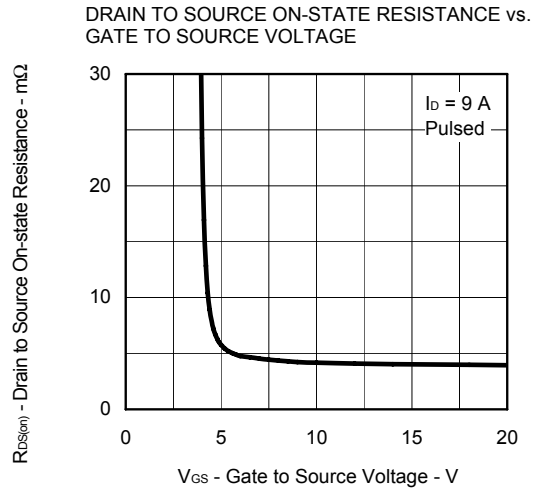
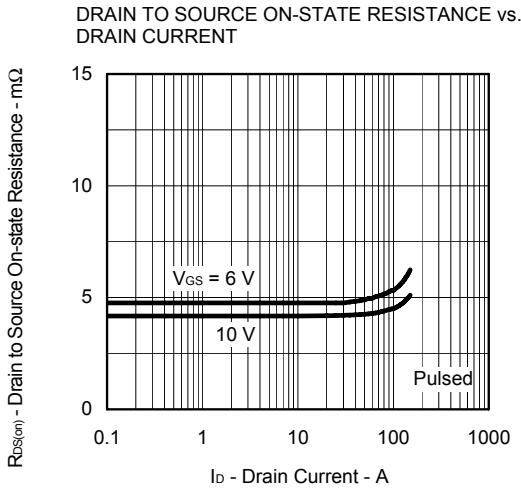
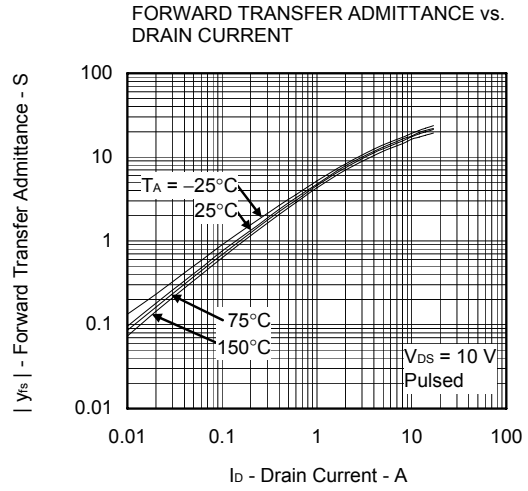
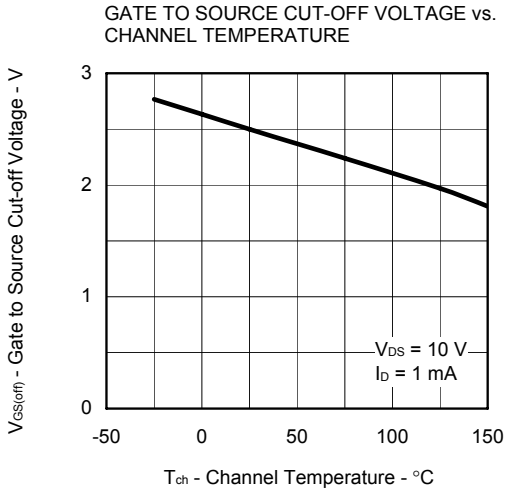


DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

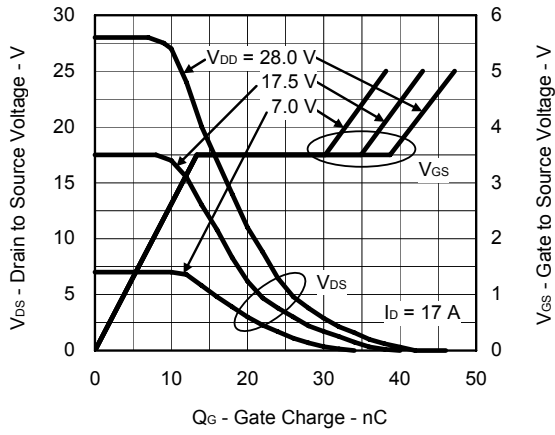


FORWARD TRANSFER CHARACTERISTICS

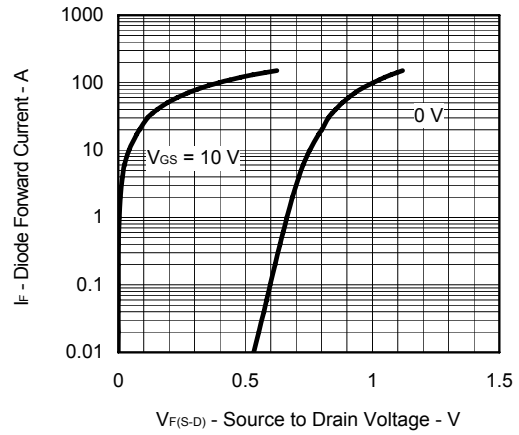




DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



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